NSN 5962-01-214-8834

Memory Microcircuit - Page 1 of 1



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Features Provided:

Bipolar and programmable and w/enable and 3-state output and monolithic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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